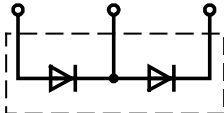
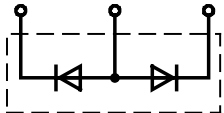
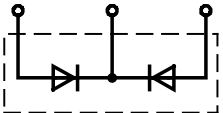


Dual Diode Water Cooled Modules MD# 950

Absolute Maximum Ratings

V_{RRM} V_{DRM} [V]	 MDD	 MDA	 MDK
1200	950-12N1W	950-12N1W	950-12N1W
1400	950-14N1W	950-14N1W	950-14N1W
1600	950-16N1W	950-16N1W	950-16N1W
1800	950-18N1W	950-18N1W	950-18N1W
2000	950-20N1W	950-20N1W	950-20N1W
2200	950-22N1W	950-22N1W	950-22N1W

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage ¹⁾	1200-2200	V
V_{RSM}	Non-repetitive peak reverse voltage ¹⁾	1300-2300	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current. $T_{water} = 17^{\circ}C$, 4l/min ^{2), 3)}	1129	A
$I_{F(AV)M}$	Maximum average forward current. $T_{water} = 45^{\circ}C$, 4l/min ^{2), 3)}	950	A
$I_{F(AV)M}$	Maximum average forward current. $T_{water} = 85^{\circ}C$, 4l/min ^{2), 3)}	668	A
$I_{F(RMS)}$	Nominal RMS forward current. $T_{water} = 17^{\circ}C$, 4l/min ^{2), 3)}	1773	A
$I_{F(D.C.)}$	D.C. forward current. $T_{water} = 17^{\circ}C$, 4l/min ³⁾	1427	A
I_{TSM}	Peak non-repetitive surge $t_p = 10$ ms, $V_{RM} = 60\%V_{RRM}$ ⁴⁾	21.8	kA
I_{TSM2}	Peak non-repetitive surge $t_p = 10$ ms, $V_{RM} \leq 10$ V ⁴⁾	24.0	kA
I^2t	I^2t capacity for fusing $t_p = 10$ ms, $V_{RM} = 60\%V_{RRM}$ ⁴⁾	2.38×10^6	A ² s
I^2t	I^2t capacity for fusing $t_p = 10$ ms, $V_{RM} \leq 10$ V ⁴⁾	2.88×10^6	A ² s
V_{isol}	Isolation Voltage ⁵⁾	3500	V
$T_{j op}$	Operating temperature range	-40 to +125	°C
$T_{j max}$	Maximum junction temperature	+150	°C
T_{stg}	Storage temperature range	-40 to +125	°C

Notes:

- 1) De-rating factor of 0.13% per °C is applicable for T_{vj} below 25°C.
- 2) Single phase; 50 Hz, 180° half-sinewave.
- 3) Current ratings do not include adjustments, which may be necessary due to heat being returned by cable connections.
- 4) Half-sinewave, 150°C T_{vj} initial.
- 5) AC RMS voltage, 50 Hz, 1min test.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS ¹⁾	UNITS
V _{FM}	Maximum peak forward voltage	-	-	1.35	I _{FM} = 2850 A	V
V _{FM}	Maximum peak forward voltage	-	-	0.88	I _{FM} = 500 A	V
V _{T0}	Threshold voltage	-	-	0.75		V
r _T	Slope resistance	-	-	0.2		mΩ
I _{RRM}	Peak reverse current	-	-	50	Rated V _{RRM}	mA
Q _{rr}	Recovered Charge	-	1800	-	I _{FM} = 1000 A, t _p = 1 ms, di/dt = 10 A/μs, V _r = 50 V	μC
Q _{ra}	Recovered Charge, 50% chord	-	1500	1750		μC
I _{rm}	Reverse recovery current	-	165	-		A
t _{rr}	Reverse recovery time, 50% chord	-	18	-		μs
R _{thJW}	Thermal resistance, junction to water	-	-	0.09	Single Diode	K/W
F ₁	Mounting force (to heatsink)	4.25	-	5.75	²⁾	Nm
F ₂	Mounting force (to terminals)	10.2	-	13.8		Nm
W _t	Weight	-	1.2	-		kg

Notes:1) Unless otherwise indicated T_{vj} = 150°C

2) Screws must be lubricated

Notes on Ratings and Characteristics**1.0 Voltage Grade Table**

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
12	1200	1300	820
14	1400	1500	930
16	1600	1700	1040
18	1800	1900	1150
20	2000	2100	1260
22	2200	2300	1370

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters**5.1 Device Dissipation Calculations**

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_K$$

Where $V_{T0}=0.75V$, $r_T=0.2m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	0.0976	0.0955	0.0942	0.0933	0.0920	0.0907	0.090
Sine wave	0.0950	0.0933	0.0924	0.0917	0.0902		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.464	2.449	2	1.732	1.414	1.149	1
Sine wave	3.98	2.778	2.22	1.879	1.57		

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		150°C Coefficients	
A	0.46164273	A	0.435837127
B	0.1048225	B	0.06435749
C	1.6116×10^{-4}	C	1.84243×10^{-4}
D	-7.48063×10^{-3}	D	-2.353947×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r_t = Thermal resistance at time t .

r_p = Amplitude of p_{th} term.

τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C.					
Term	1	2	3	4	5
r_p	0.07972	3.64310×10^{-3}	4.87795×10^{-3}	1.91134×10^{-3}	2.16406×10^{-3}
τ_p	4.46119	0.71394	0.06312	5.07740×10^{-3}	6.07258×10^{-3}

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{RM} chord as shown in Fig. 1

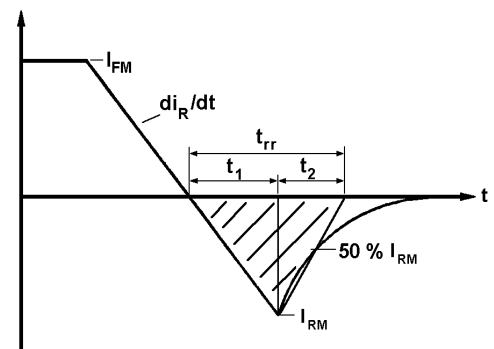


Fig. 1

(ii) Q_{rr} is based on a $150 \mu s$ integration time i.e.

$$Q_{rr} = \int_0^{150 \mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

Curves

Figure 1 - Forward characteristics of Limit device

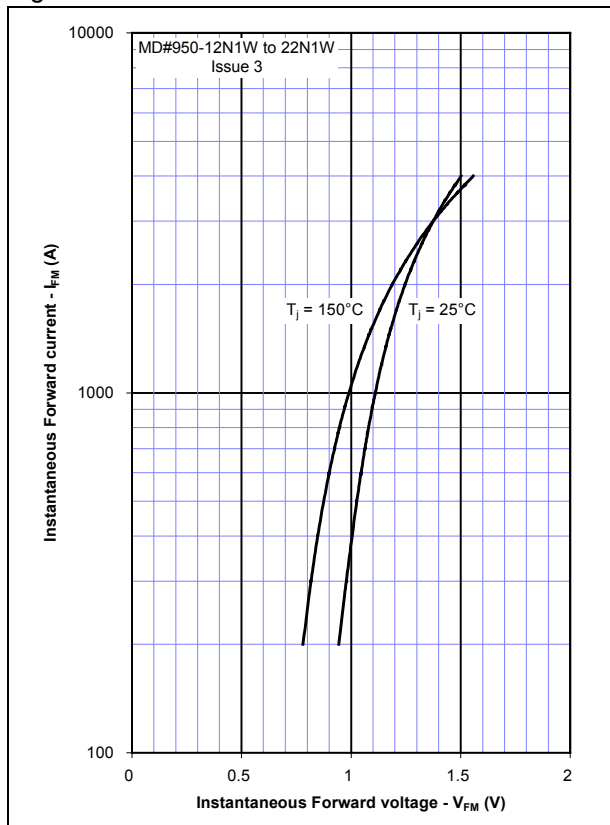


Figure 2 - Transient thermal impedance

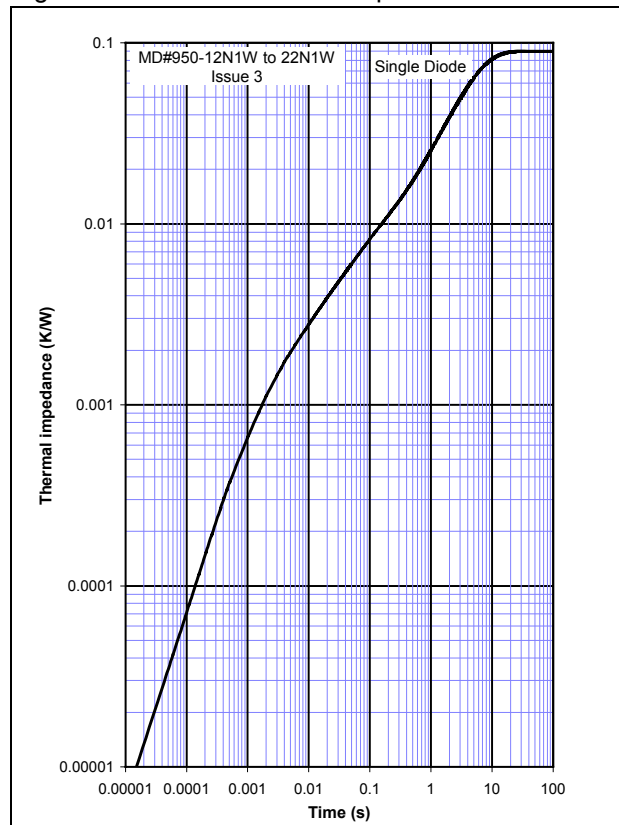


Figure 3 – Average forward current and Power loss Vs. Inlet water temperature

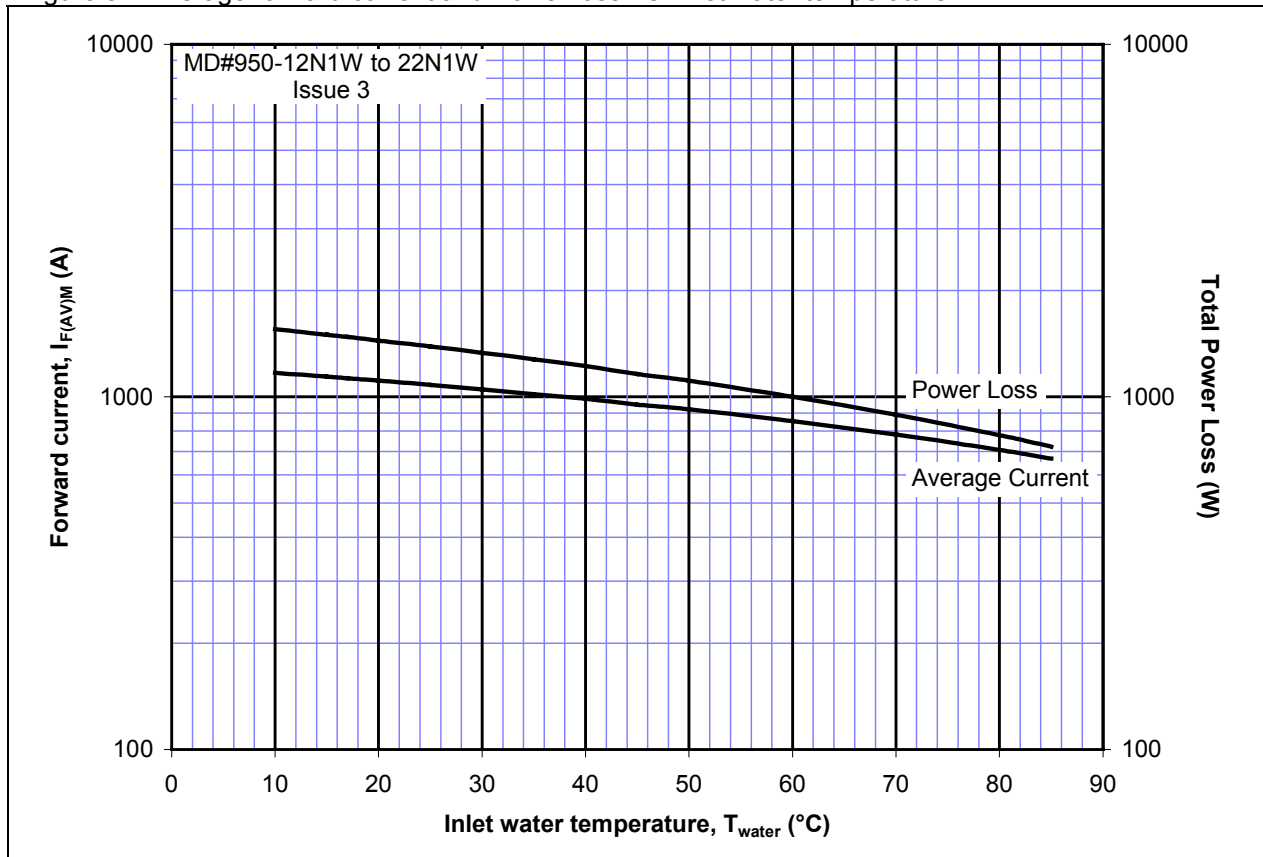


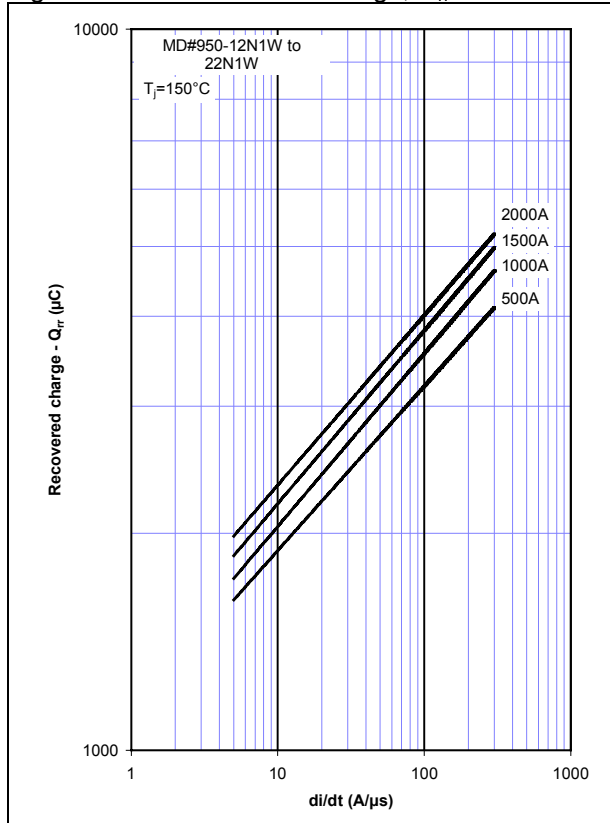
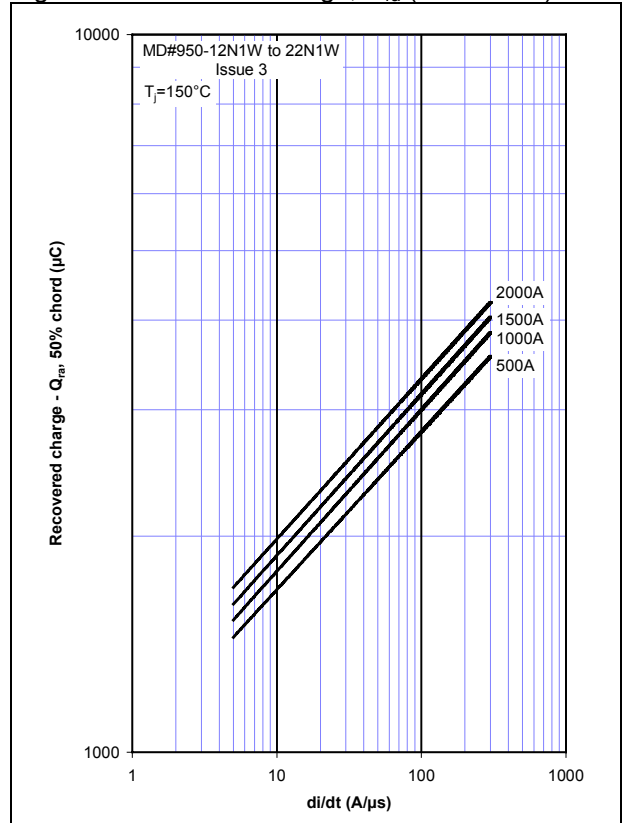
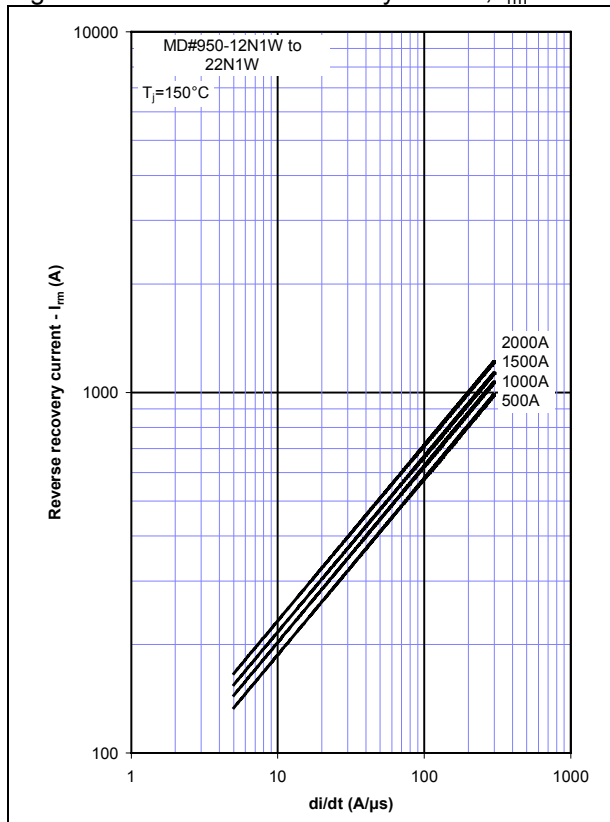
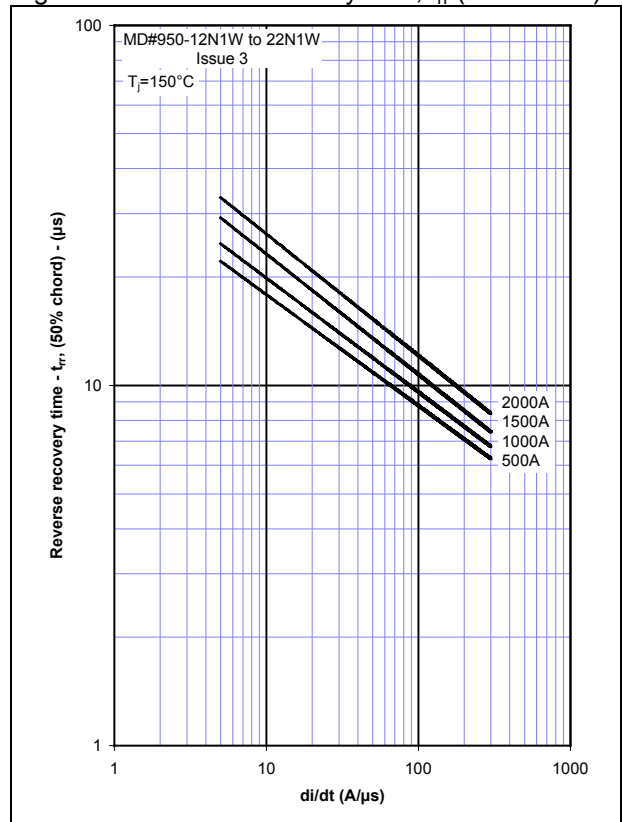
Figure 4 - Total recovered charge, Q_{rr} Figure 5 - Recovered charge, Q_{ra} (50% chord)Figure 6 - Peak reverse recovery current, I_{rm} Figure 7 - Maximum recovery time, t_{rr} (50% chord)

Figure 8 – Forward current vs. Power dissipation

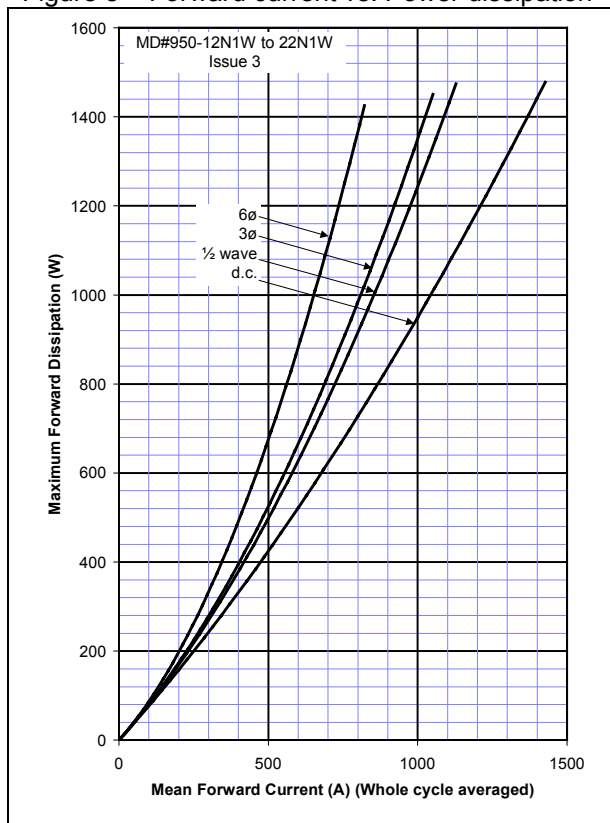


Figure 9 – Forward current vs. Water temperature

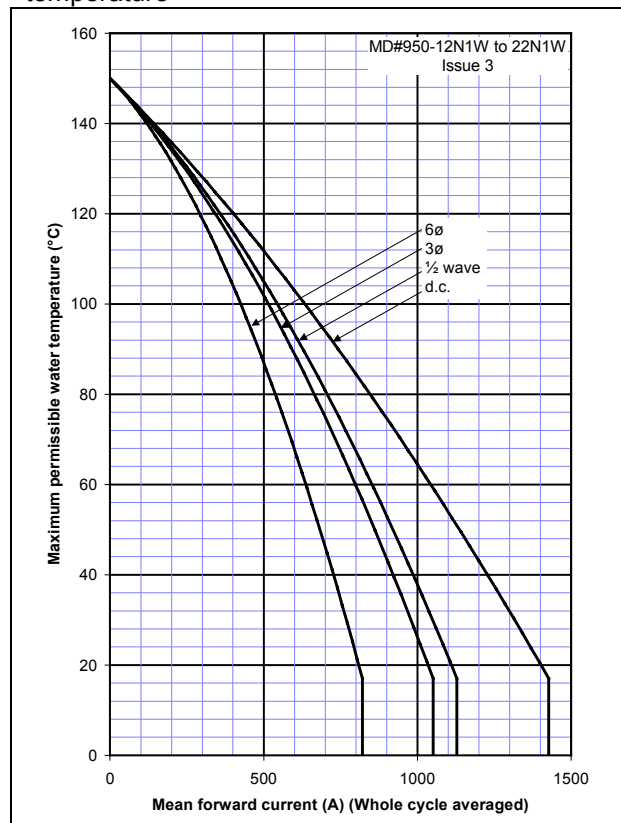
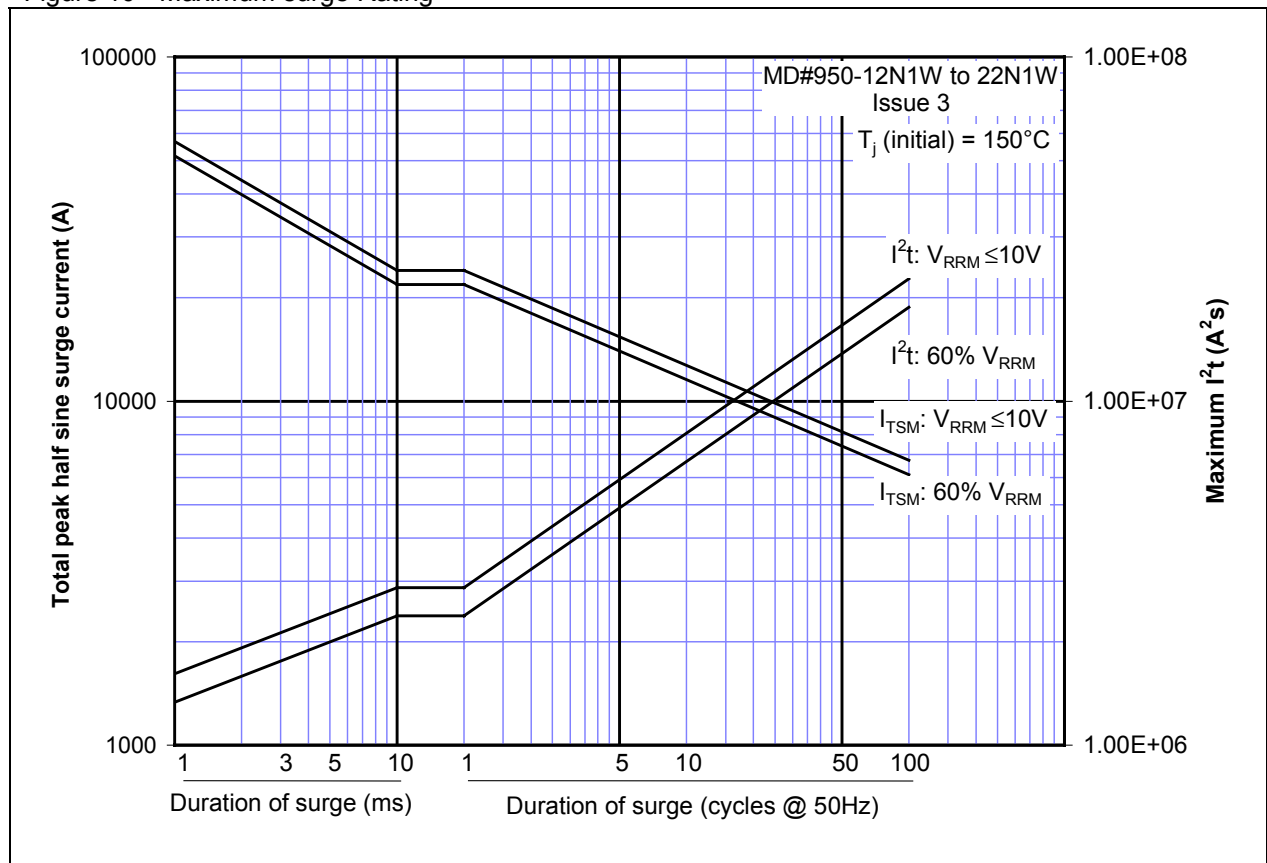
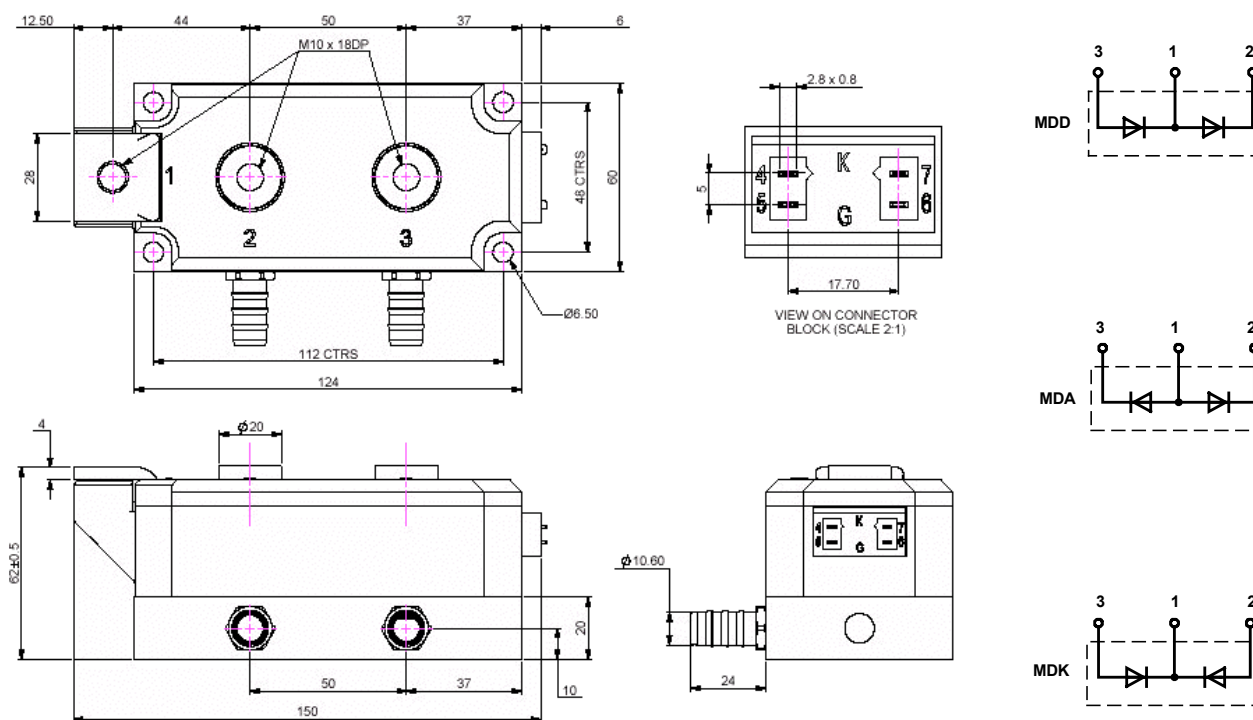


Figure 10 - Maximum surge Rating



Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 11 digit code as below)

M	D#	950	◆◆	N	1	W
Fixed Type Code	Configuration code DD, DA, DK	Average Current Rating	Voltage code $V_{DRM}/100$ 12-22	Standard diode	Fixed Version Code	Water cooled base

Order code: MDD950-14N1W— MDD configuration, 1400V V_{DRM} , V_{RRM} , water cooled base

IXYS Semiconductor GmbH

Edisonstraße 15
D-68623 Lampertheim
Tel: +49 6206 503-0
Fax: +49 6206 503-627
E-mail: marcom@ixys.de

www.ixys.com

Westcode Semiconductors Ltd

Langley Park Way, Langley Park,
Chippenham, Wiltshire, SN15 1GE.
Tel: +44 (0)1249 444524
Fax: +44 (0)1249 659448
E-mail: WSL.sales@westcode.com

WESTCODE

An IXYS Company

www.westcode.com

IXYS Corporation

3540 Bassett Street
Santa Clara CA 95054 USA
Tel: +1 (408) 982 0700
Fax: +1 (408) 496 0670
E-mail: sales@ixys.net

Westcode Semiconductors Inc

3270 Cherry Avenue
Long Beach CA 90807 USA
Tel: +1 (562) 595 6971
Fax: +1 (562) 595 8182
E-mail: WSL.sales@westcode.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS Semiconductors GmbH.

© IXYS Semiconductor GmbH.

In the interest of product improvement, IXYS reserves the right to change specifications at any time without prior notice.